

# MUN2111T1 Series

Preferred Devices

## Bias Resistor Transistors

### PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: Class 1  
– Machine Model: Class B
- The SC-59 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Pb-Free Package is Available

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	I <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW °C/W
Thermal Resistance – Junction-to-Ambient	R <sub>θJA</sub>	540 (Note 1) 370 (Note 2)	°C/W
Thermal Resistance – Junction-to-Lead	R <sub>θJL</sub>	264 (Note 1) 287 (Note 2)	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

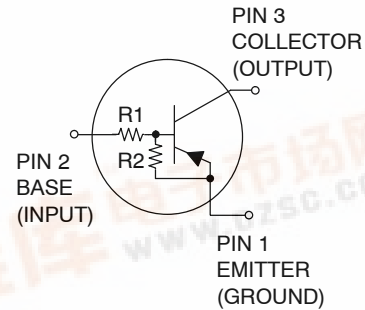
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 inch Pad.



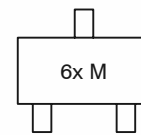
ON Semiconductor®

<http://onsemi.com>



SC-59  
CASE 318D  
PLASTIC

#### MARKING DIAGRAM



6x = Specific Device Code\*  
M = Date Code

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

#### DEVICE MARKING INFORMATION

\*See device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.



## MUN2111T1 Series

### DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping <sup>†</sup>
MUN2111T1	SC-59	6A	10	10	3000 / Tape & Reel
MUN2111T1G	SC-59 (Pb-Free)	6A	10	10	3000 / Tape & Reel
MUN2112T1	SC-59	6B	22	22	3000 / Tape & Reel
MUN2112T1G	SC-59 (Pb-Free)	6B	22	22	3000 / Tape & Reel
MUN2113T1	SC-59	6C	47	47	3000 / Tape & Reel
MUN2113T1G	SC-59 (Pb-Free)	6C	47	47	3000 / Tape & Reel
MUN2114T1	SC-59	6D	10	47	3000 / Tape & Reel
MUN2114T1G	SC-59 (Pb-Free)	6D	10	47	3000 / Tape & Reel
MUN2115T1 (Note 3)	SC-59	6E	10	∞	3000 / Tape & Reel
MUN2116T1 (Note 3)	SC-59	6F	4.7	∞	3000 / Tape & Reel
MUN2116T1G (Note 3)	SC-59 (Pb-Free)	6F	4.7	∞	3000 / Tape & Reel
MUN2130T1 (Note 3)	SC-59	6G	1.0	1.0	3000 / Tape & Reel
MUN2131T1 (Note 3)	SC-59	6H	2.2	2.2	3000 / Tape & Reel
MUN2132T1 (Note 3)	SC-59	6J	4.7	4.7	3000 / Tape & Reel
MUN2132T1G (Note 3)	SC-59 (Pb-Free)	6J	4.7	4.7	3000 / Tape & Reel
MUN2133T1 (Note 3)	SC-59	6K	4.7	47	3000 / Tape & Reel
MUN2134T1 (Note 3)	SC-59	6L	22	47	3000 / Tape & Reel
MUN2136T1	SC-59	6N	100	100	3000 / Tape & Reel
MUN2137T1	SC-59	6P	47	22	3000 / Tape & Reel
MUN2140T1 (Note 3)	SC-59	6T	47	∞	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. New resistor combinations. Updated curves to follow in subsequent data sheets.

## MUN2111T1 Series

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}$ , $I_E = 0$ )	$I_{CBO}$	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )	$I_{CEO}$	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$	-	-	0.5	mAdc
MUN2111T1		-	-	0.2	
MUN2112T1		-	-	0.1	
MUN2113T1		-	-	0.2	
MUN2114T1		-	-	0.9	
MUN2115T1		-	-	1.9	
MUN2116T1		-	-	4.3	
MUN2130T1		-	-	2.3	
MUN2131T1		-	-	1.5	
MUN2132T1		-	-	0.18	
MUN2133T1		-	-	0.13	
MUN2134T1		-	-	0.05	
MUN2136T1		-	-	0.13	
MUN2137T1		-	-	0.20	
MUN2140T1		-	-		
Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}$ , $I_E = 0$ )	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 4) ( $I_C = 2.0\text{ mA}$ , $I_B = 0$ )	$V_{(BR)CEO}$	50	-	-	Vdc

### ON CHARACTERISTICS (Note 4)

DC Current Gain ( $V_{CE} = 10\text{ V}$ , $I_C = 5.0\text{ mA}$ )	$h_{FE}$	35	60	-	
MUN2111T1		60	100	-	
MUN2112T1		80	140	-	
MUN2113T1		80	140	-	
MUN2114T1		160	250	-	
MUN2115T1		160	250	-	
MUN2116T1		3.0	5.0	-	
MUN2130T1		8.0	15	-	
MUN2131T1		15	27	-	
MUN2132T1		80	140	-	
MUN2133T1		80	130	-	
MUN2134T1		80	150	-	
MUN2136T1		80	140	-	
MUN2137T1		120	250	-	
MUN2140T1					
Collector-Emitter Saturation Voltage ( $I_C = 10\text{ mA}$ , $I_B = 0.3\text{ mA}$ )	$V_{CE(sat)}$	-	-	0.25	Vdc
MUN2111T1		-	-	0.25	
MUN2112T1		-	-	0.25	
MUN2113T1		-	-	0.25	
MUN2114T1		-	-	0.25	
MUN2115T1		-	-	0.25	
MUN2130T1		-	-	0.25	
MUN2136T1		-	-	0.25	
MUN2137T1		-	-	0.25	
( $I_C = 10\text{ mA}$ , $I_B = 5.0\text{ mA}$ )		-	-	0.25	
MUN2131T1		-	-	0.25	
( $I_C = 10\text{ mA}$ , $I_B = 1.0\text{ mA}$ )		-	-	0.25	
MUN2116T1		-	-	0.25	
MUN2132T1		-	-	0.25	
MUN2134T1		-	-	0.25	
MUN2140T1		-	-	0.25	
Output Voltage (on) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 2.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	$V_{OL}$	-	-	0.2	Vdc
MUN2111T1		-	-	0.2	
MUN2112T1		-	-	0.2	
MUN2114T1		-	-	0.2	
MUN2115T1		-	-	0.2	
MUN2116T1		-	-	0.2	
MUN2130T1		-	-	0.2	
MUN2131T1		-	-	0.2	
MUN2132T1		-	-	0.2	
MUN2133T1		-	-	0.2	
MUN2134T1		-	-	0.2	
( $V_{CC} = 5.0\text{ V}$ , $V_B = 3.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )		-	-	0.2	
MUN2113T1		-	-	0.2	
MUN2140T1		-	-	0.2	
( $V_{CC} = 5.0\text{ V}$ , $V_B = 5.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )		-	-	0.2	
MUN2136T1		-	-	0.2	
( $V_{CC} = 5.0\text{ V}$ , $V_B = 4.0\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )		-	-	0.2	
MUN2137T1		-	-	0.2	

4. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%.

# MUN2111T1 Series

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b> (Note 4)					
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.050\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.25\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )	$V_{OH}$	4.9	–	–	Vdc
Input Resistor	R1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 70 32.9 32.9	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 100 47 47	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 130 61.1 61.1	k $\Omega$
Resistor Ratio	$R_1/R_2$	0.8 0.17 – 0.8 0.055 0.38 1.7	1.0 0.21 – 1.0 0.1 0.47 2.1	1.2 0.25 – 1.2 0.185 0.56 2.6	

4. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%.

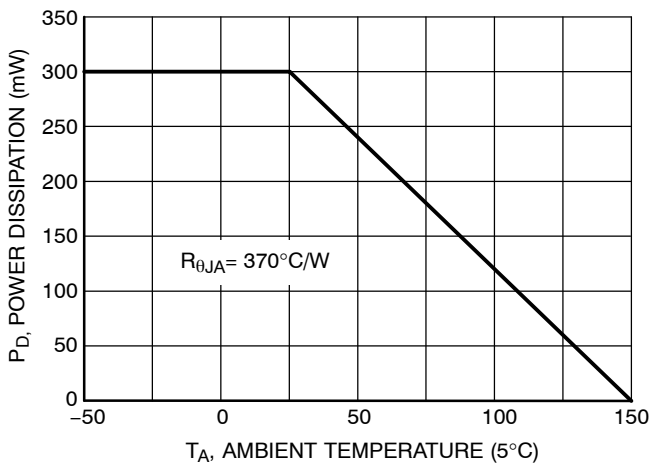


Figure 1. Derating Curve

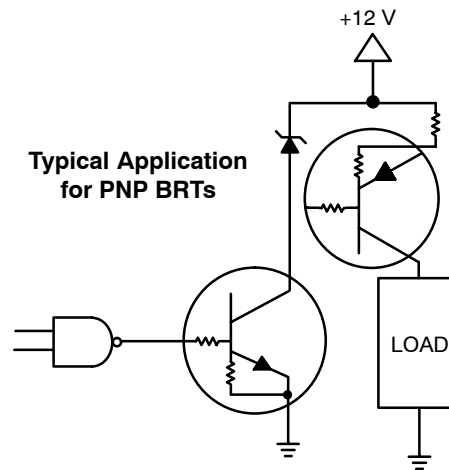


Figure 2. Inexpensive, Unregulated Current Source

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MUN2111T1

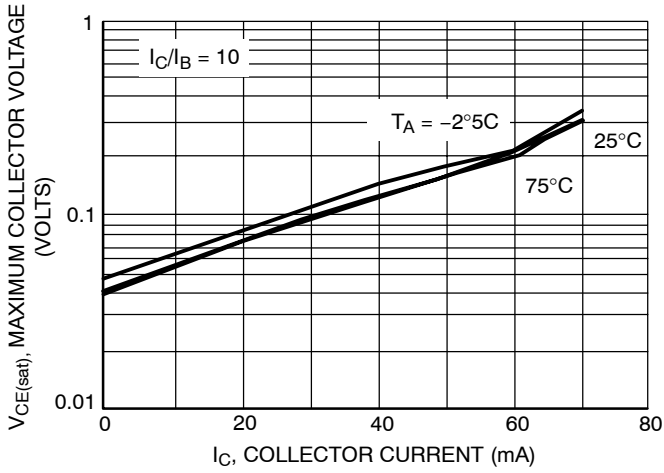


Figure 3.  $V_{CE(sat)}$  vs.  $I_C$

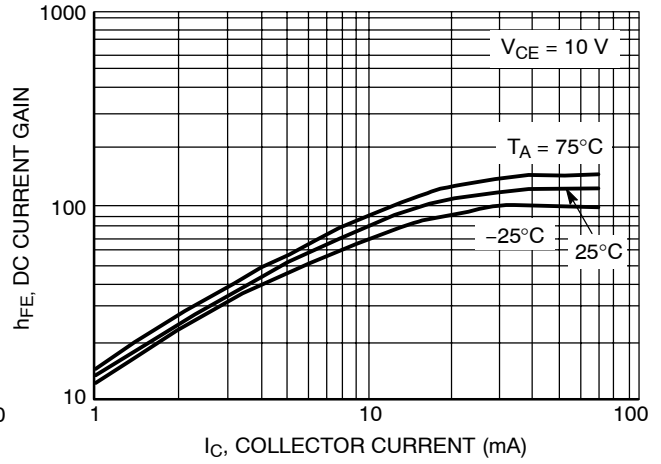


Figure 4. DC Current Gain

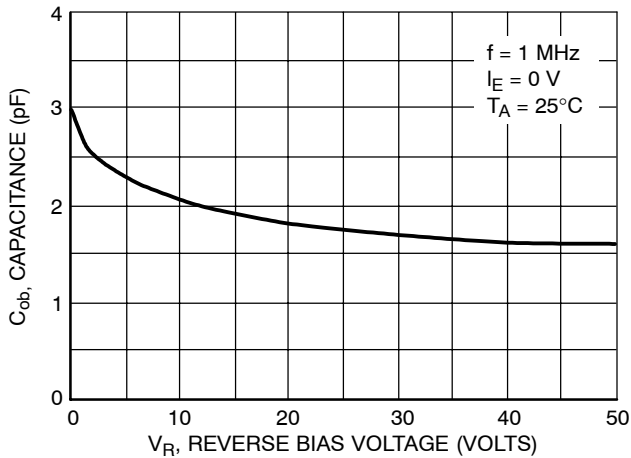


Figure 5. Output Capacitance

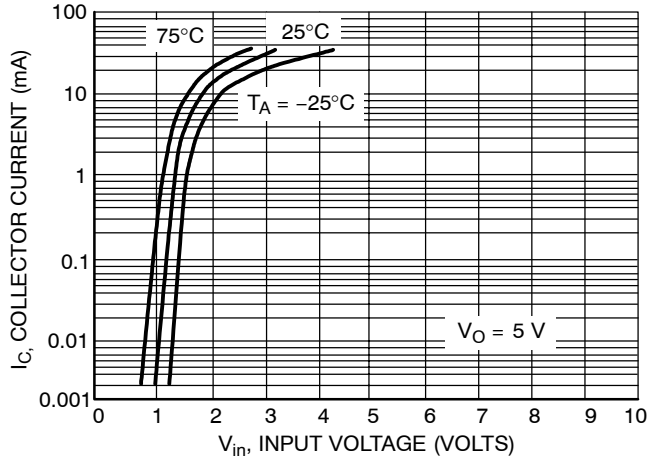


Figure 6. Output Current vs. Input Voltage

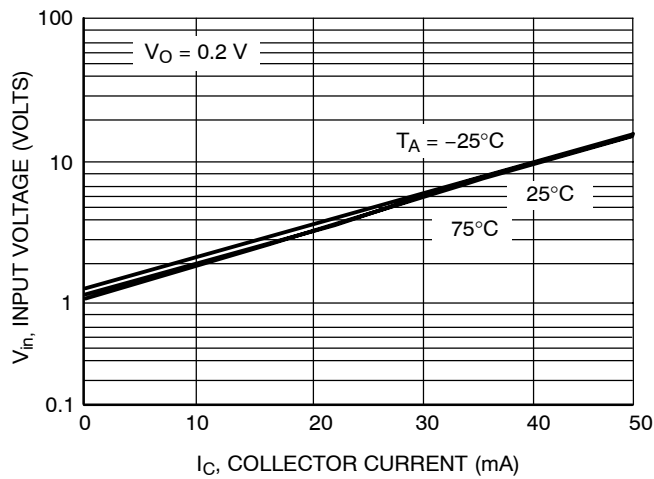


Figure 7. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MUN2112T1

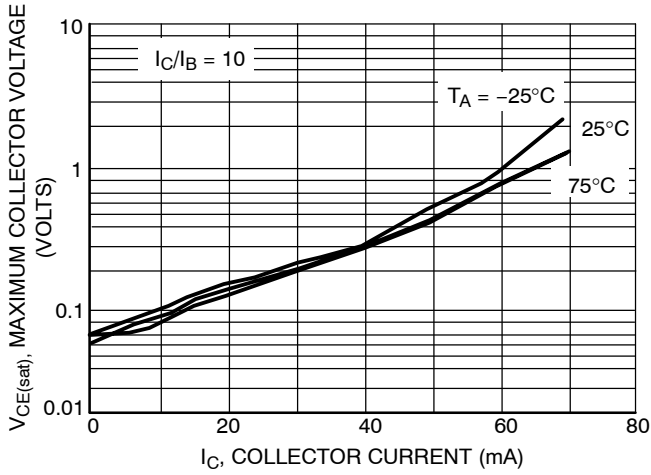


Figure 8.  $V_{CE(sat)}$  vs.  $I_C$

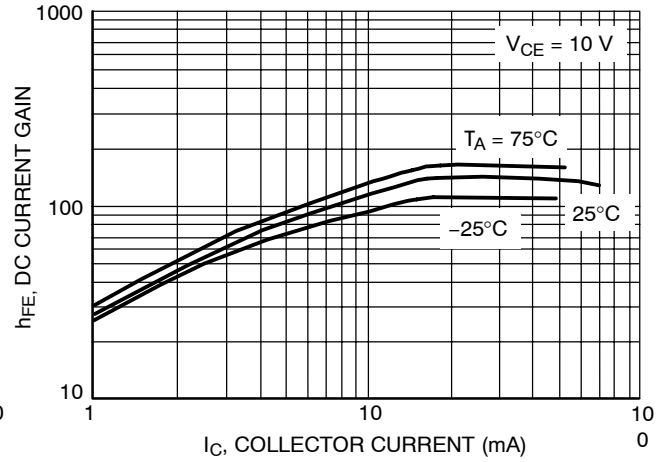


Figure 9. DC Current Gain

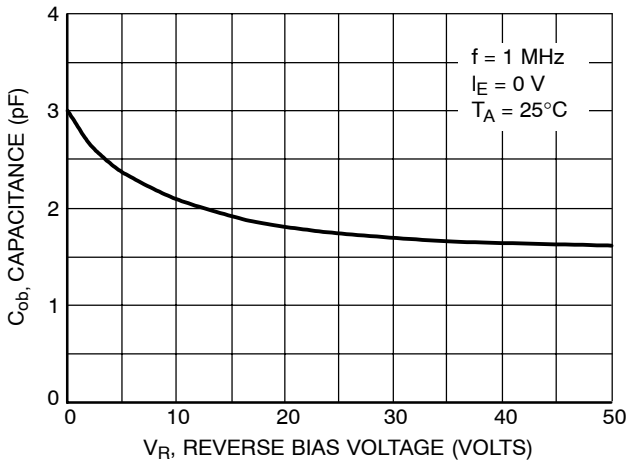


Figure 10. Output Capacitance

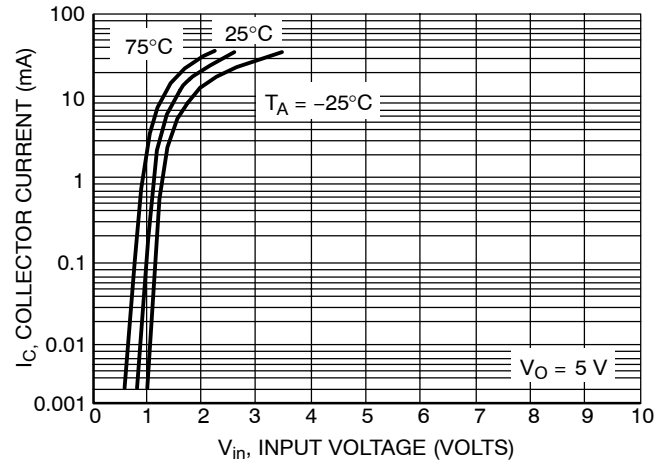


Figure 11. Output Current vs. Input Voltage

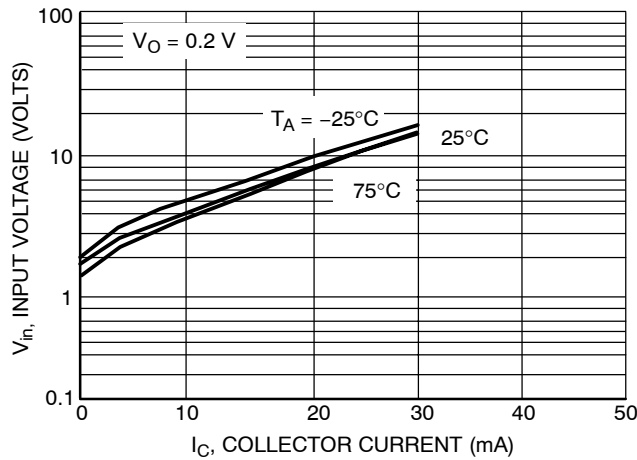


Figure 12. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MUN2113T1

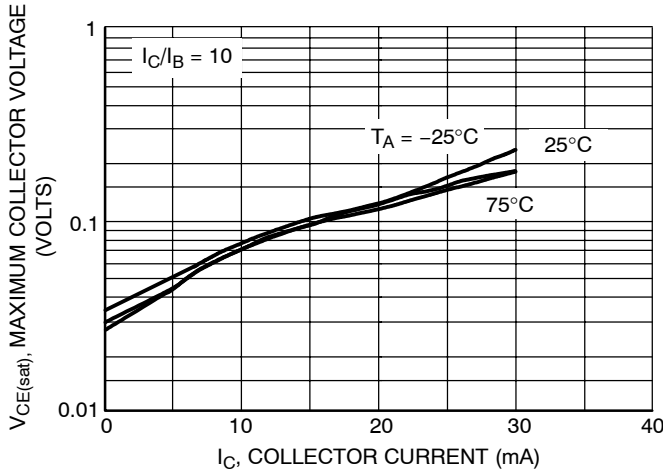


Figure 13.  $V_{CE(sat)}$  vs.  $I_C$

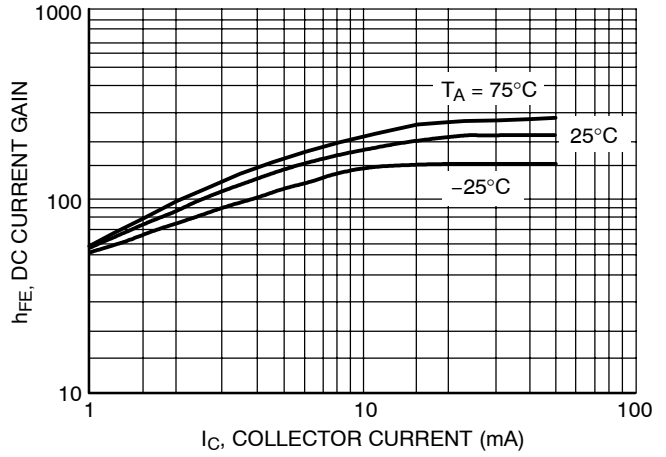


Figure 14. DC Current Gain

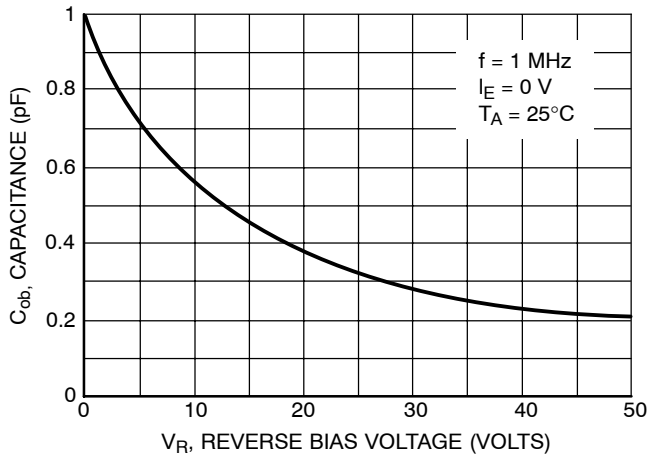


Figure 15. Output Capacitance

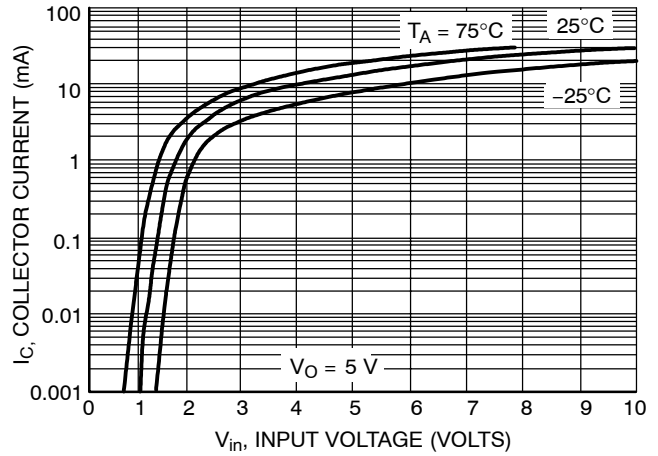


Figure 16. Output Current vs. Input Voltage

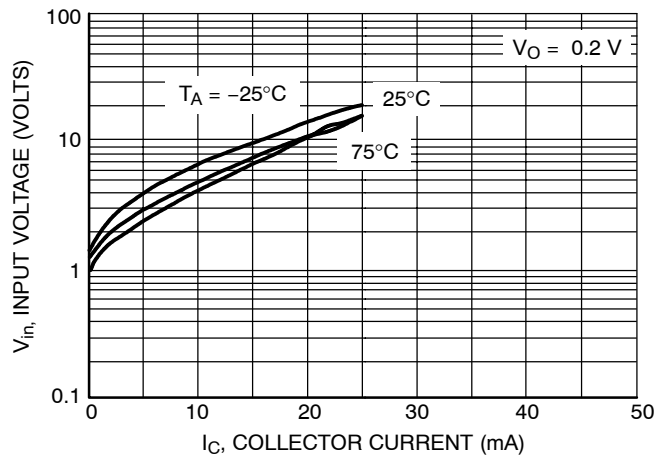


Figure 17. Input Voltage vs. Output Current

# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MUN2114T1

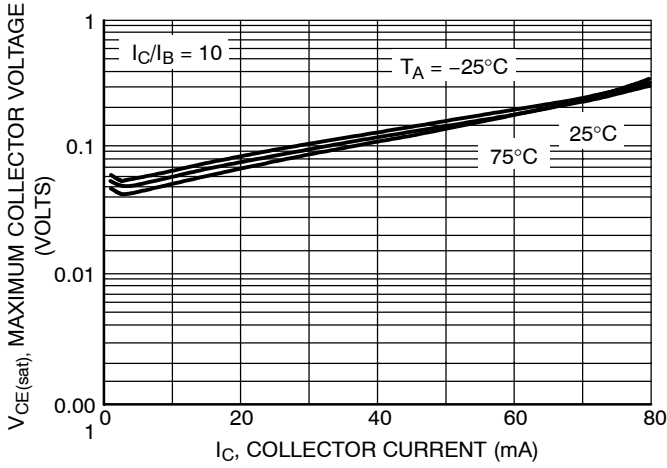


Figure 18.  $V_{CE(sat)}$  vs.  $I_C$

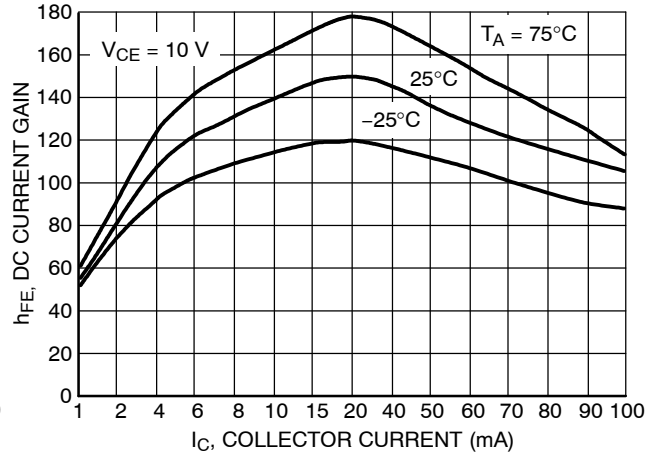


Figure 19. DC Current Gain

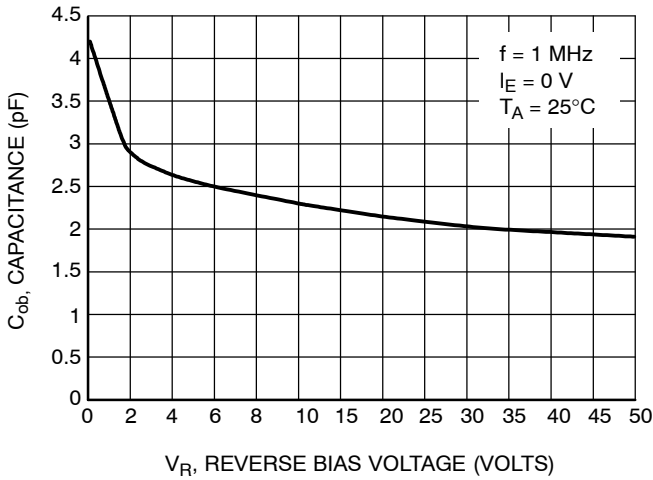


Figure 20. Output Capacitance

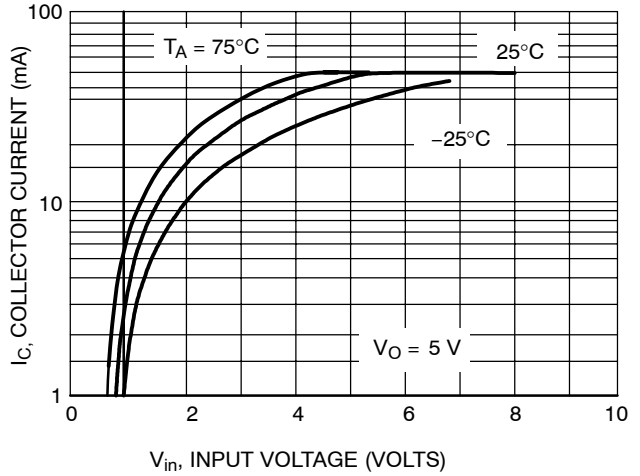


Figure 21. Output Current vs. Input Voltage

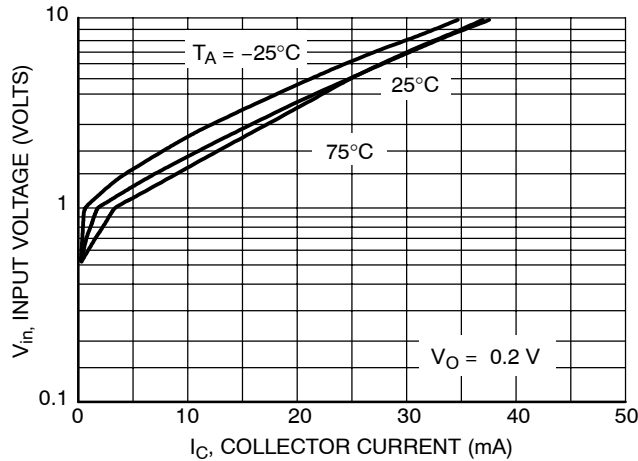


Figure 22. Input Voltage vs. Output Current



# MUN2111T1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS - MUN2131T1

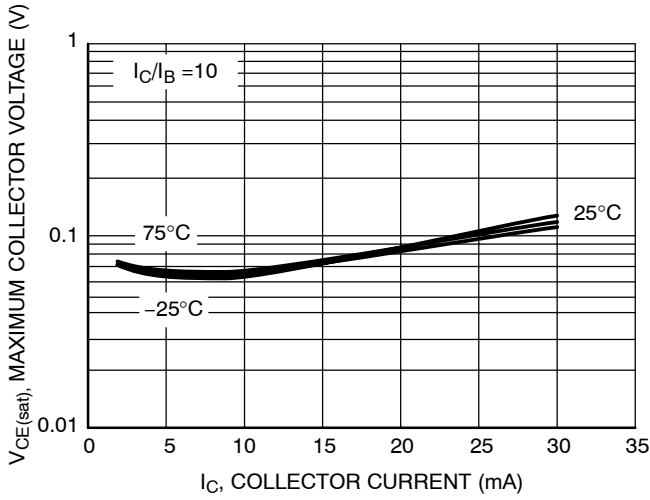


Figure 23.  $V_{CE(sat)}$  vs.  $I_C$

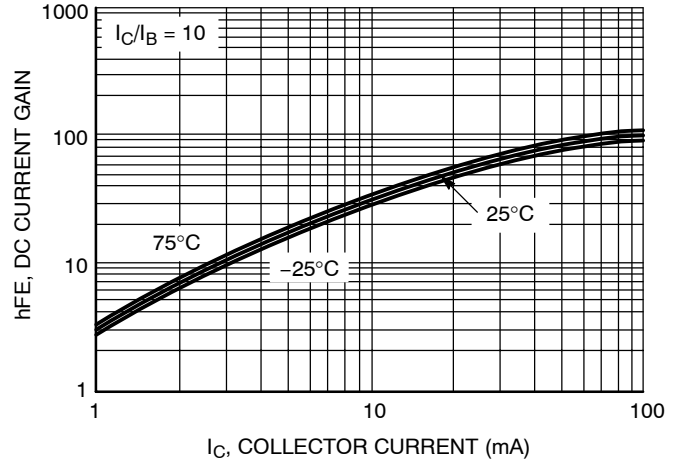


Figure 24. DC Current Gain

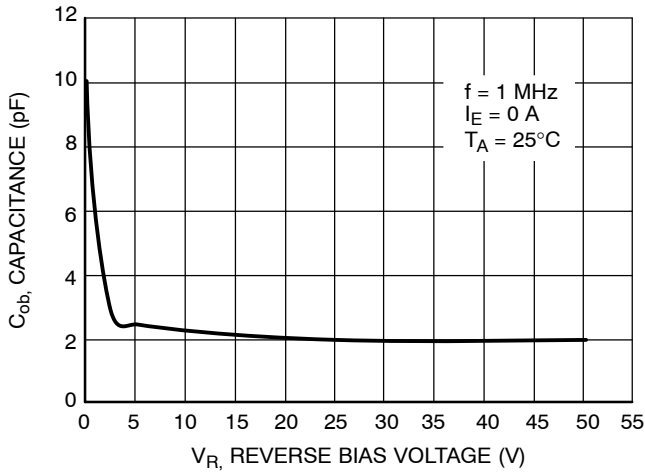


Figure 25. Output Capacitance

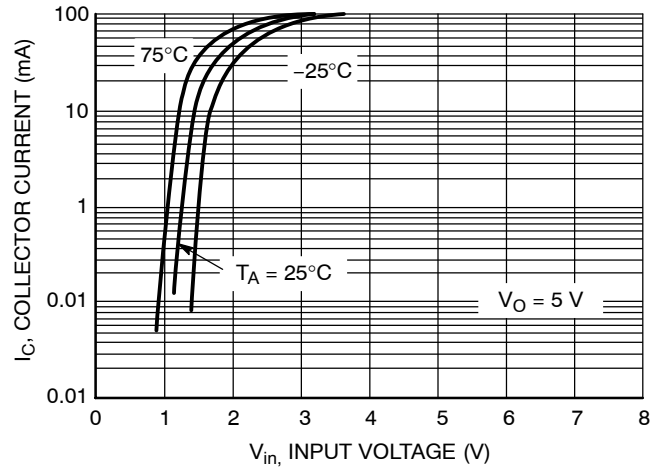


Figure 26. Output Current vs. Input Voltage

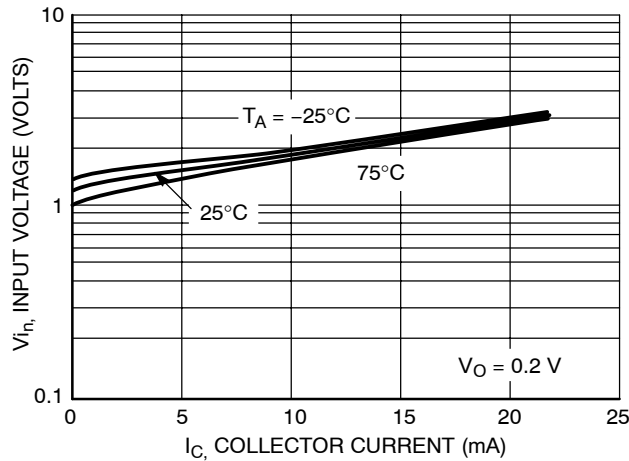
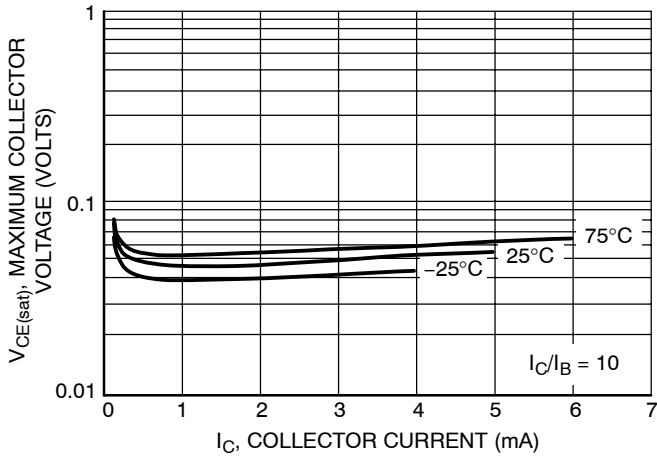


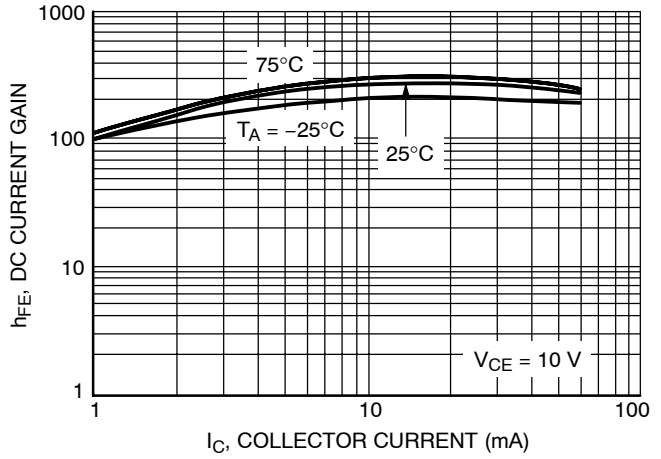
Figure 27. Input Voltage vs. Output Current

# MUN2111T1 Series

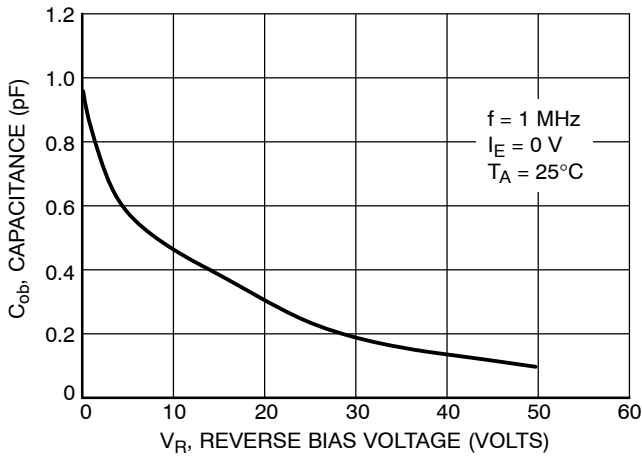
## TYPICAL ELECTRICAL CHARACTERISTICS — MUN2136T1



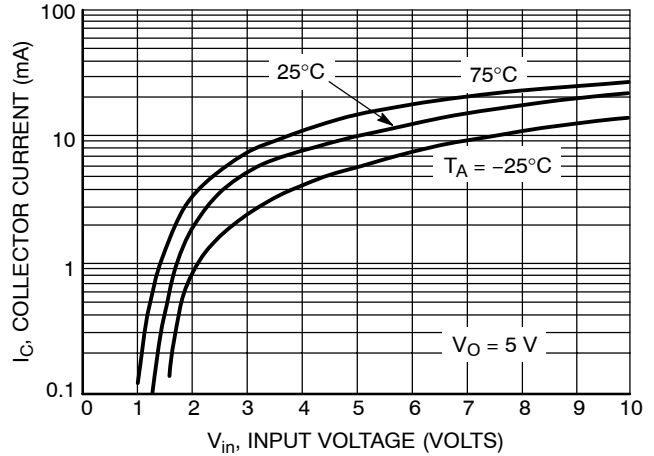
**Figure 28. Maximum Collector Voltage vs. Collector Current**



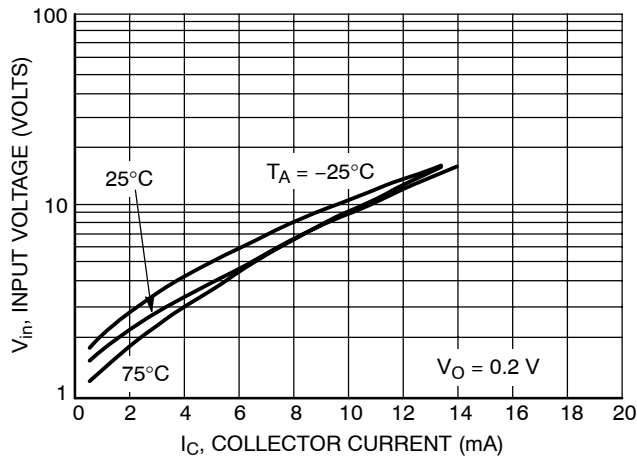
**Figure 29. DC Current Gain**



**Figure 30. Output Capacitance**



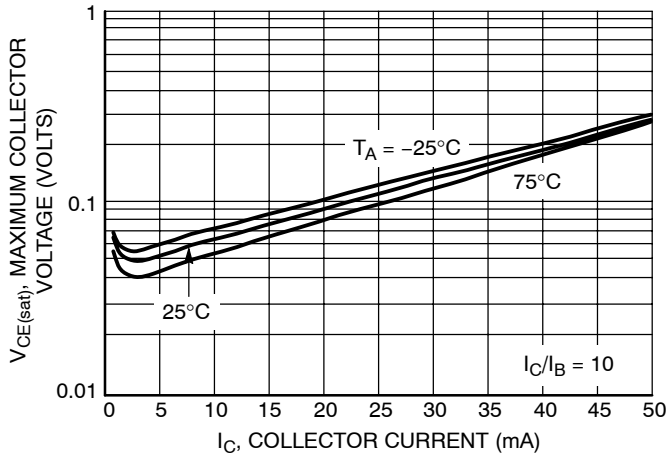
**Figure 31. Output Current vs. Input Voltage**



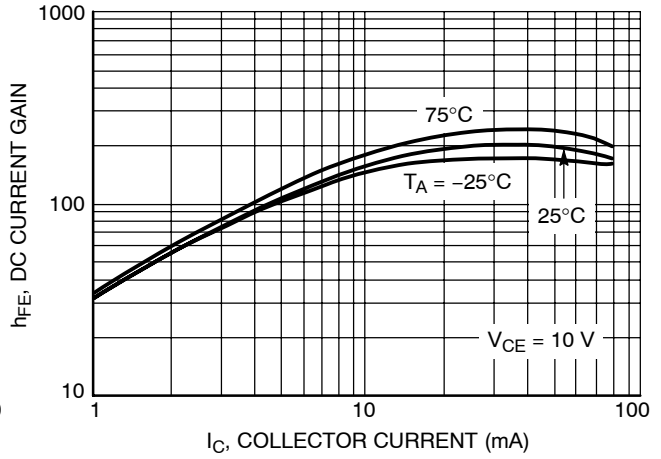
**Figure 32. Input Voltage vs. Output Current**

# MUN2111T1 Series

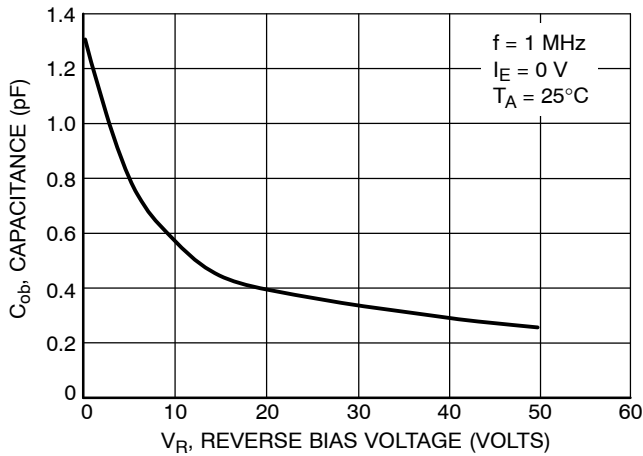
## TYPICAL ELECTRICAL CHARACTERISTICS — MUN2137T1



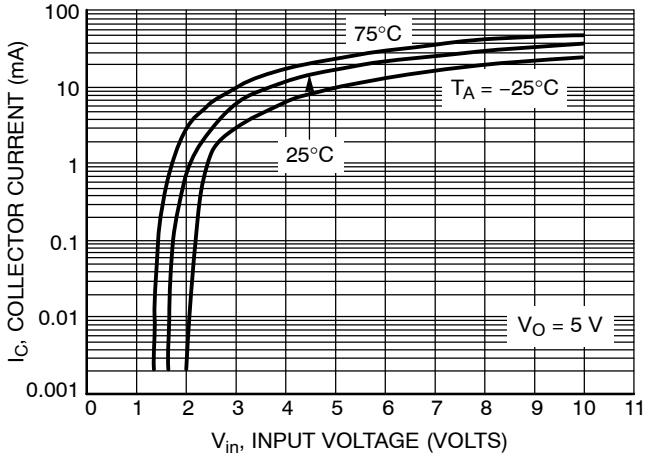
**Figure 33. Maximum Collector Voltage vs. Collector Current**



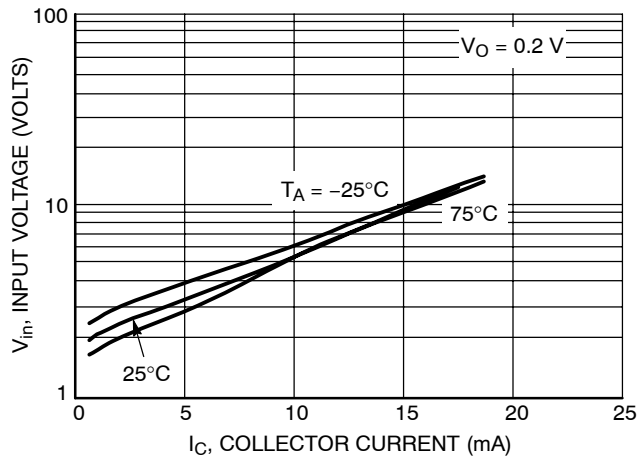
**Figure 34. DC Current Gain**



**Figure 35. Output Capacitance**



**Figure 36. Output Current vs. Input Voltage**

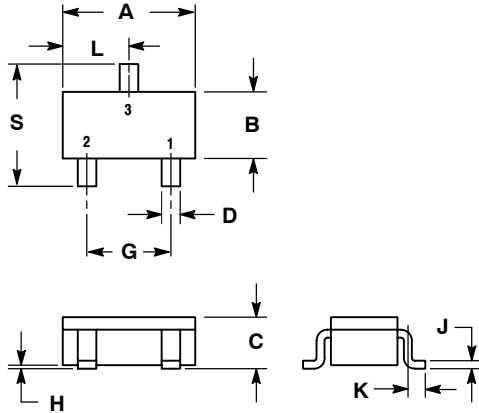


**Figure 37. Input Voltage vs. Output Current**

# MUN2111T1 Series

## PACKAGE DIMENSIONS

SC-59  
CASE 318D-04  
ISSUE F



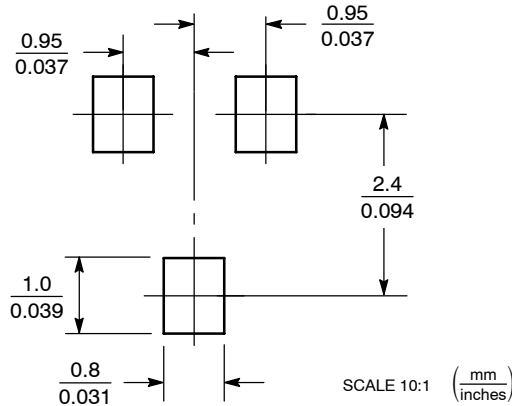
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.1063	0.1220
B	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
H	0.013	0.100	0.0005	0.0040
J	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181

STYLE 1:  
PIN 1. EMITTER  
2. BASE  
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**

Literature Distribution Center for ON Semiconductor  
P.O. Box 61312, Phoenix, Arizona 85082-1312 USA  
Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada  
Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada  
Email: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada

**Japan:** ON Semiconductor, Japan Customer Focus Center  
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051  
Phone: 81-3-5773-3850

**ON Semiconductor Website:** <http://onsemi.com>

**Order Literature:** <http://www.onsemi.com/litorder>

For additional information, please contact your local Sales Representative.